

Low Temperature Co-fired Heterogeneous Ferrite Planar Inductor for High Density Power Applications



M. J. Tung*, W. S. Ko, Y. T. Haung, S. Y. Tong and M. D. Yang
Material and Chemical Research Laboratories
Industrial Technology Research Institute, Taiwan

Outline

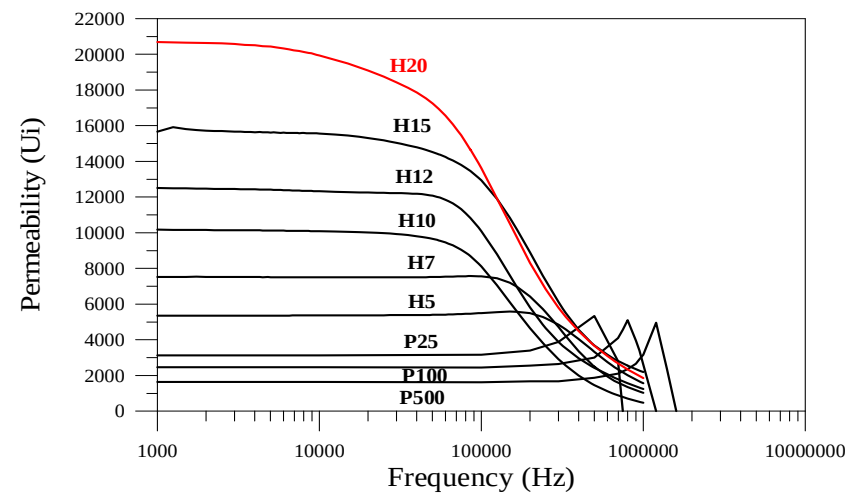
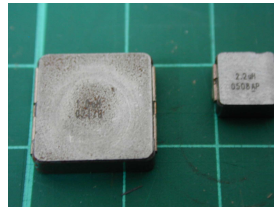
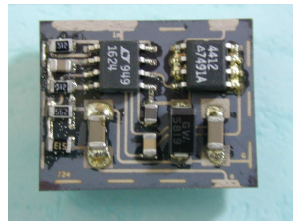
- Introduction
- 2D/3D magnetic simulation of heterogeneous multilayer power inductors
- Process, components and modules
- Summary

Magnetic laboratory in ITRI

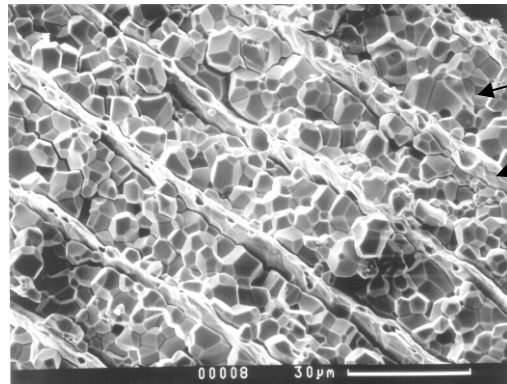
Since 1984

Focus on soft/hard magnetic materials and components for power and EMI applications

More than 60 case of technology transferred to Taiwan local industries for mass production



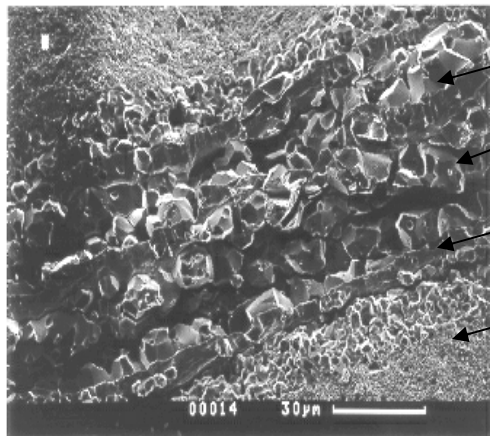
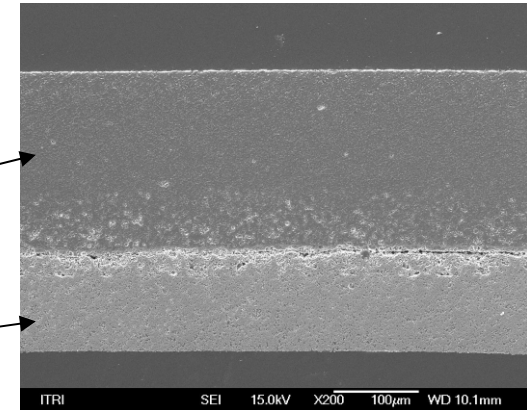
ITRI's Co-fire ceramics



BaTiO₃
Ag electrode

LTCC

Ferrite



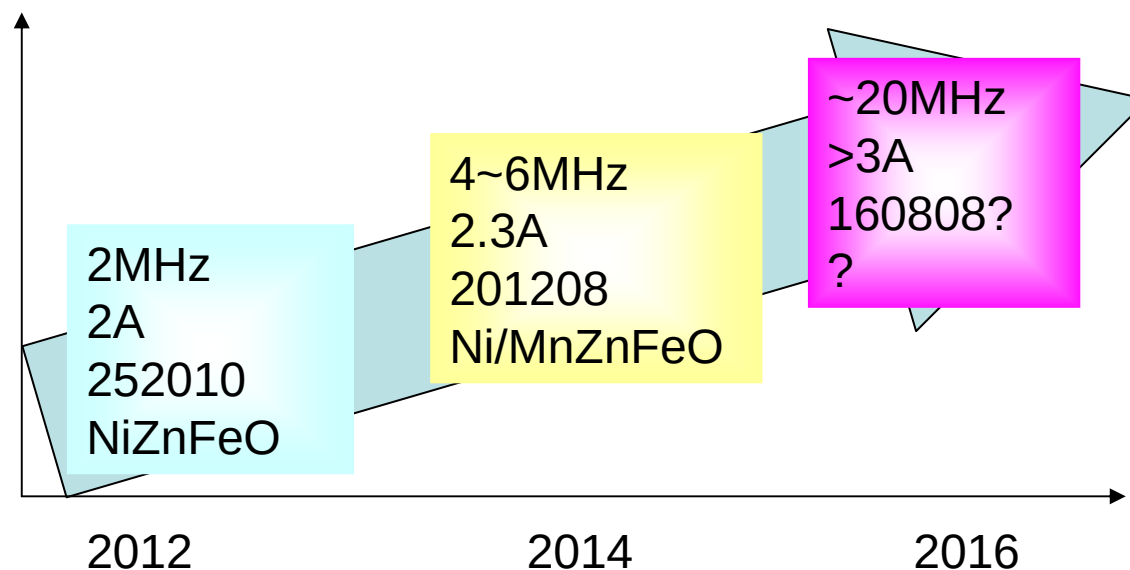
Relaxer dielectric material
Ag electrode
Relaxer dielectric material
Ferrite

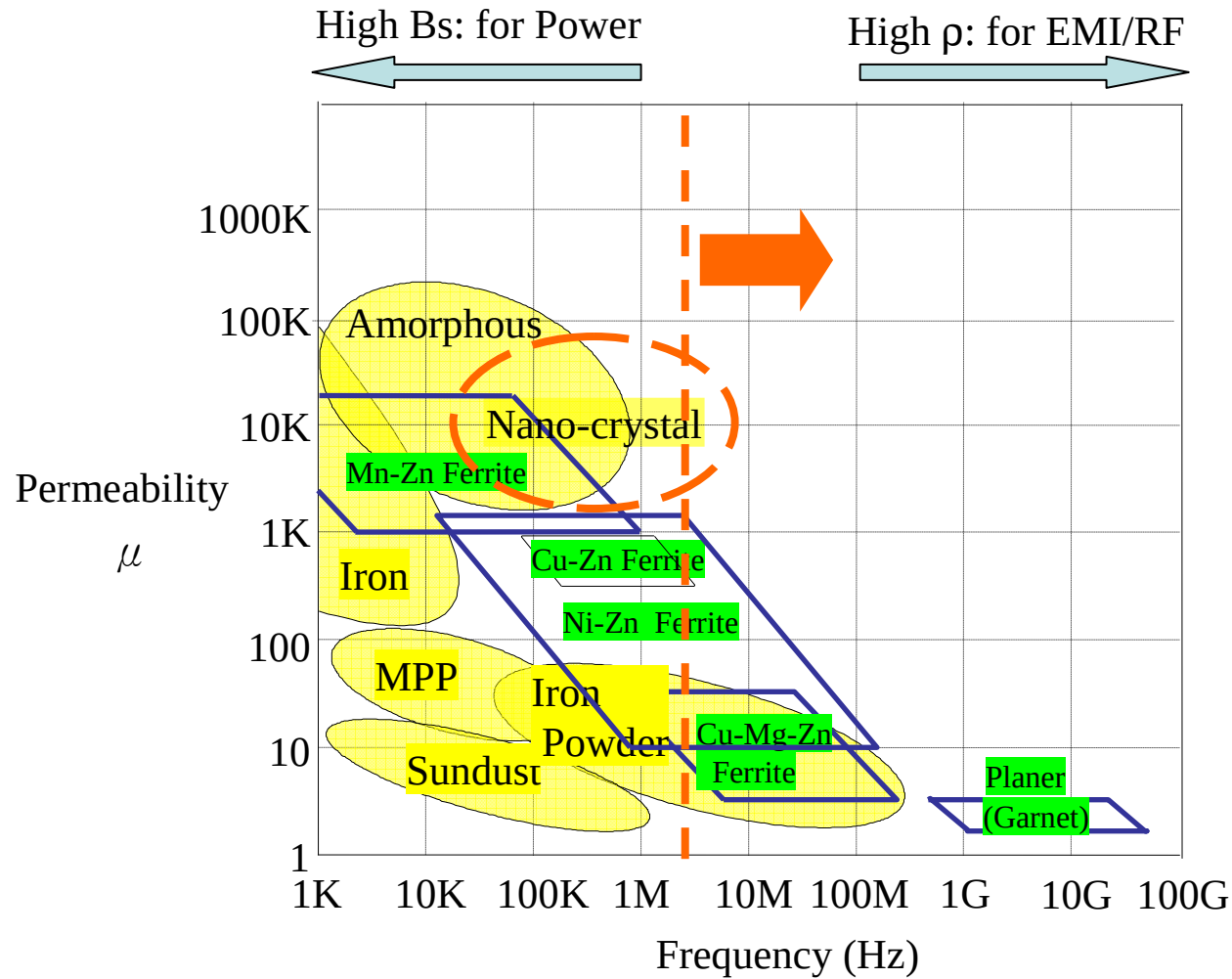
MgFeO dielectric
Ferrite



Trend of power inductor for mobile devices

- The development of power inductors toward high frequency and high current density. While approaching the limitation of material properties
- Integration of materials, winding, active/passive components and circuit will improve both the working frequency and power density.
- Low temperature co-fired ferrite may provide a reasonable solution mobile devices





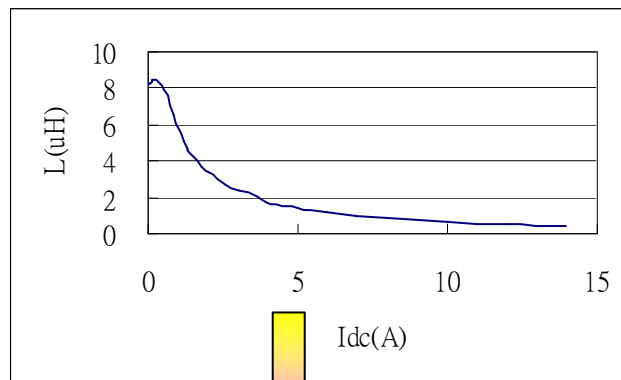
2D/3D simulation of ML power inductors

Database of non-linear BH curve of ferrites

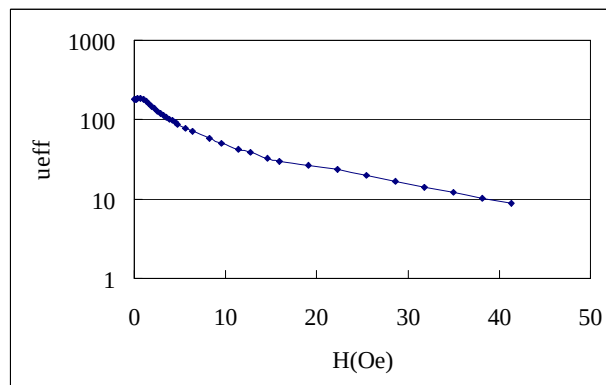
Model of multilayer power inductors for magnetic circuit analysis



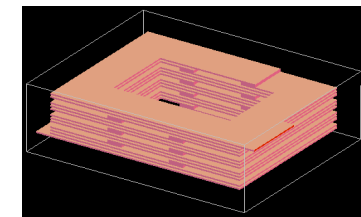
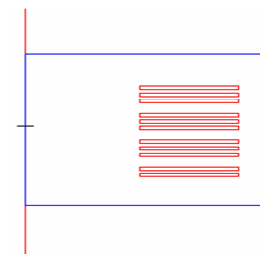
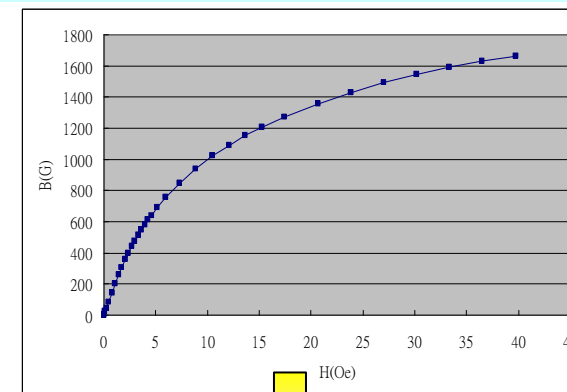
Measurement of L-Idc



μ -f/ μ -H/ μ -T...



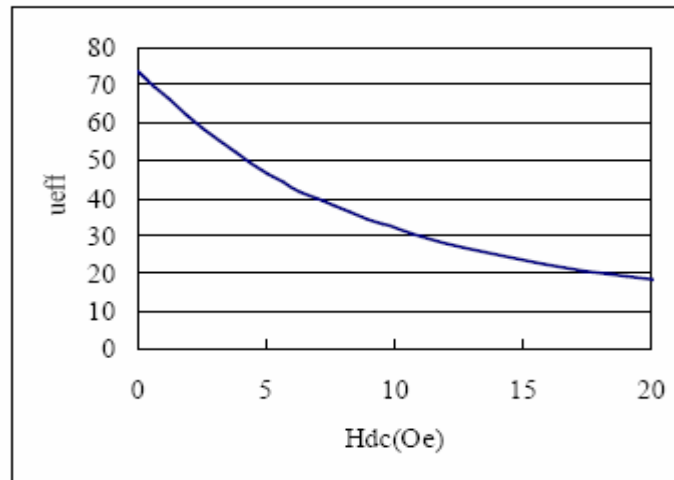
Non-linear B-H response



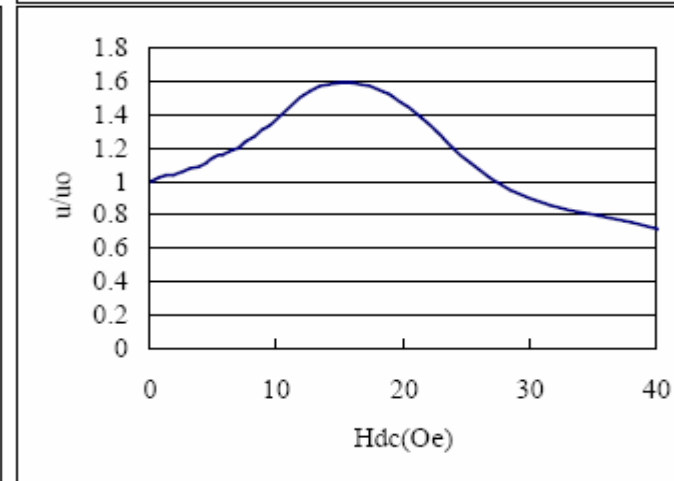
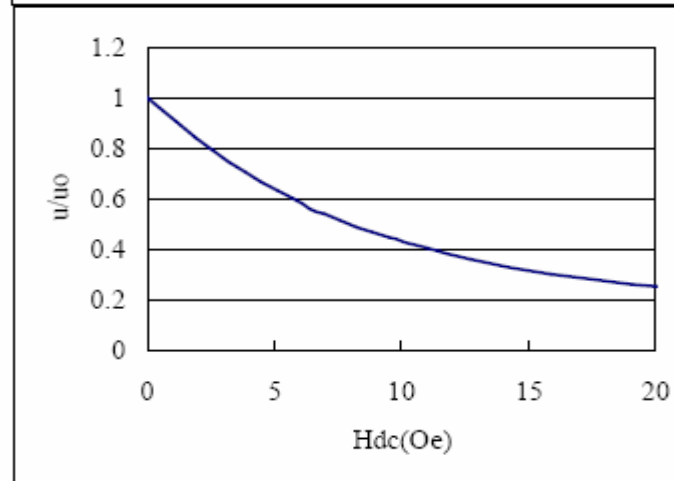
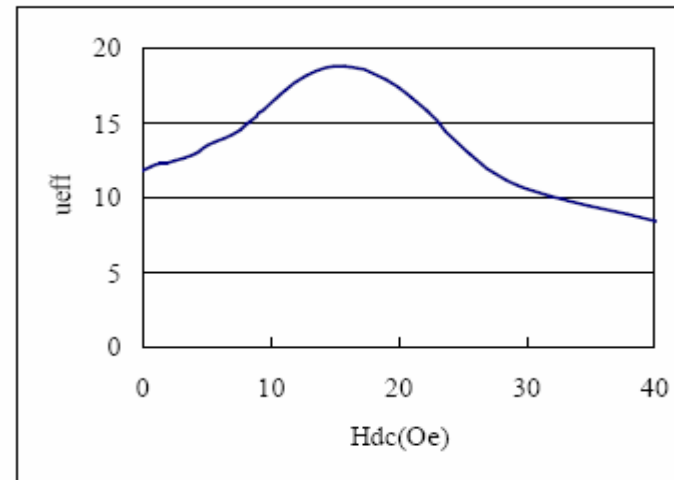
Use the material properties for the simulation will improve the accuracy of results

μ -H properties:

TR12



TR021

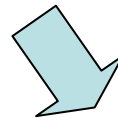
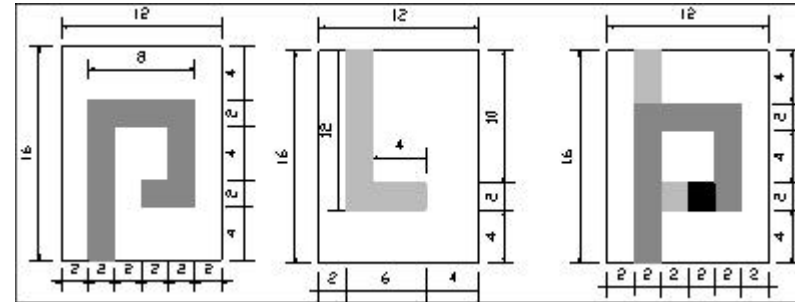


$u_i \sim 120$, $B_s \geq 3700$ Gauss

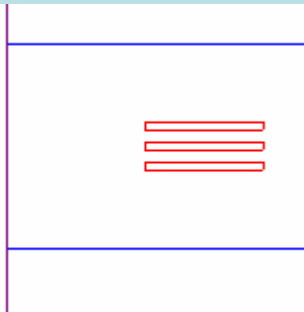
$u_i \sim 20$, B_s 值 ≥ 2000 Gauss

2D simulation

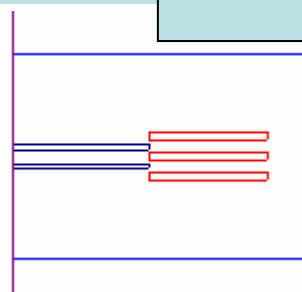
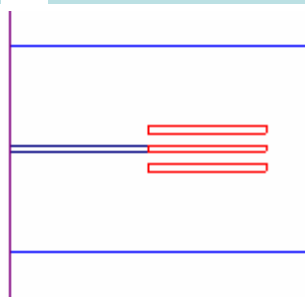
Chip size: 2.3x1.85x0.8mm
Coil pattern: 1.2x0.75mm
N=2~9 - $\frac{3}{4}$ turn/layer
Line width: 0.4mm
Line thickness: 30um
Ferrite Thickness: 20um



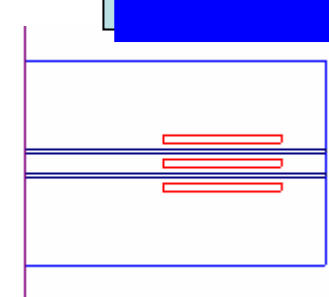
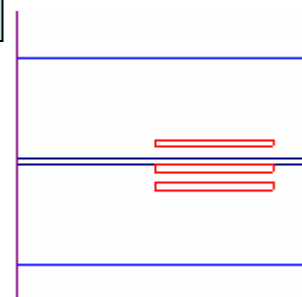
**Without
insertion layer**
• pure TR12
• pure TR021



TR12 + TR021 insert layer
Insert in center area
• Single layer
• Two layer

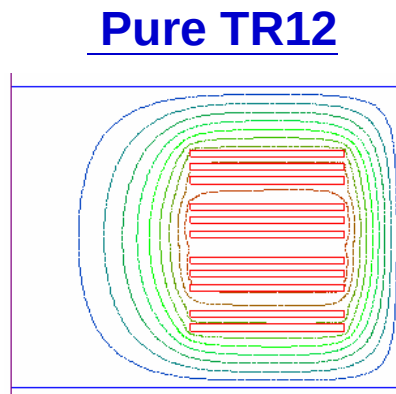
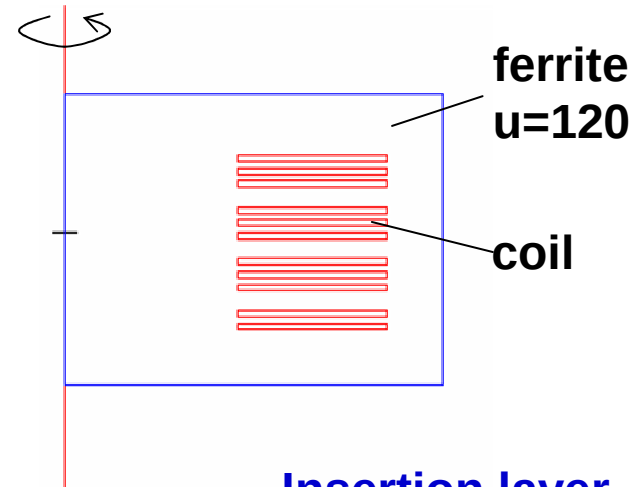


TR12 + TR021 insert layer
Insert a full layer
• Single layer
• Two layer

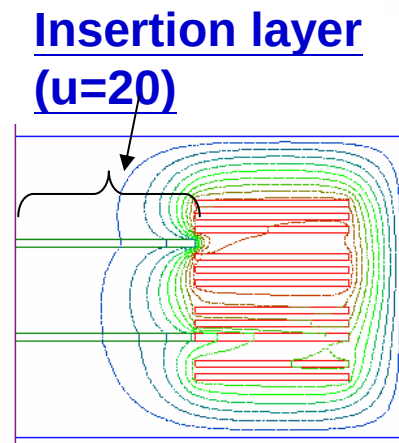


2D model

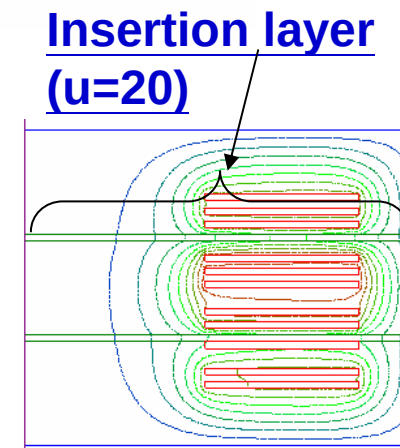
$$U = \frac{1}{2} L I^2 = \frac{1}{2} \int H \cdot B d\Omega$$



• L=10.7uH

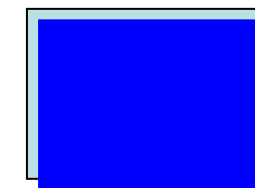
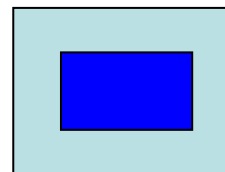
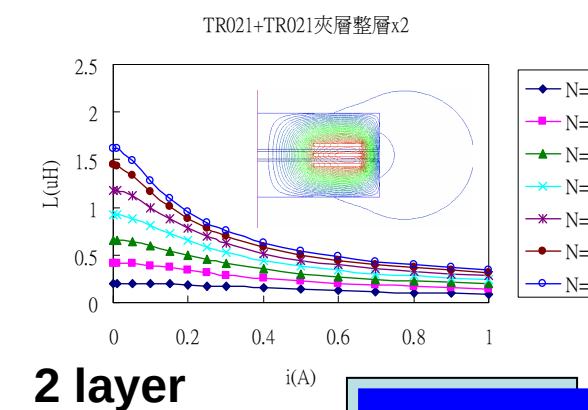
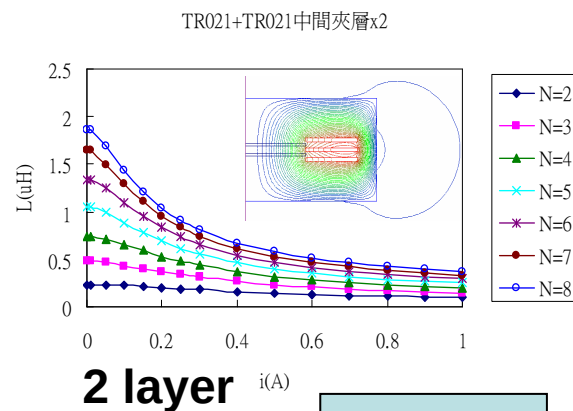
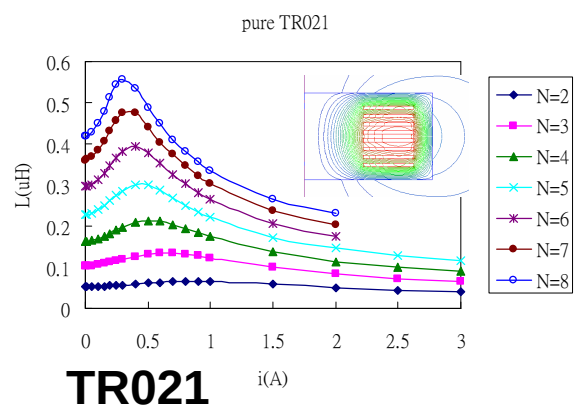
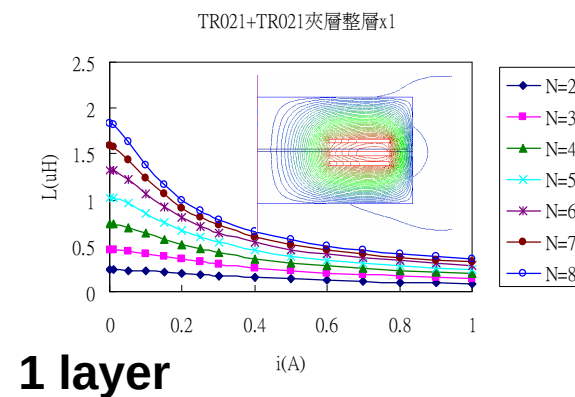
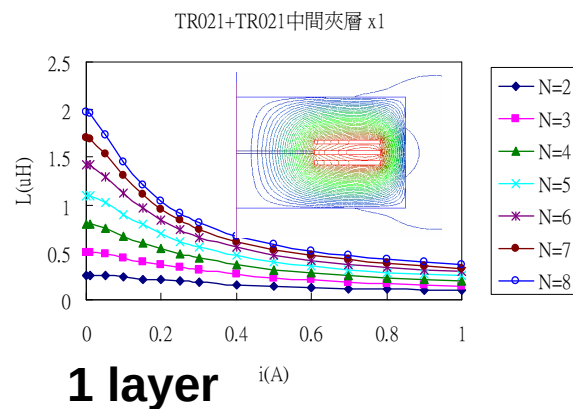
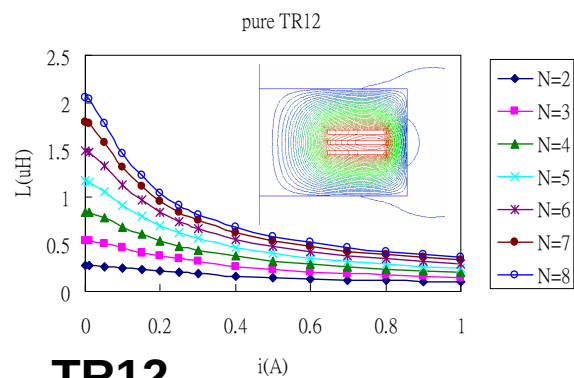


• L=4.9uH



• L=3.05uH

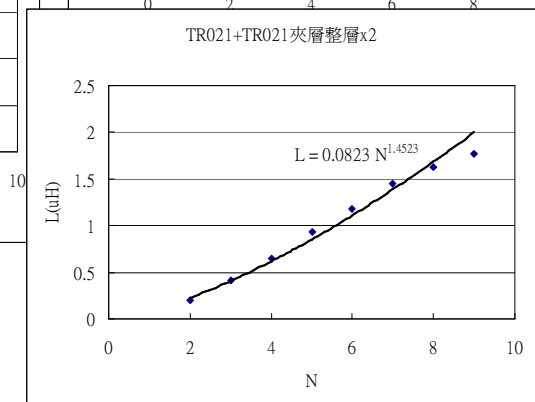
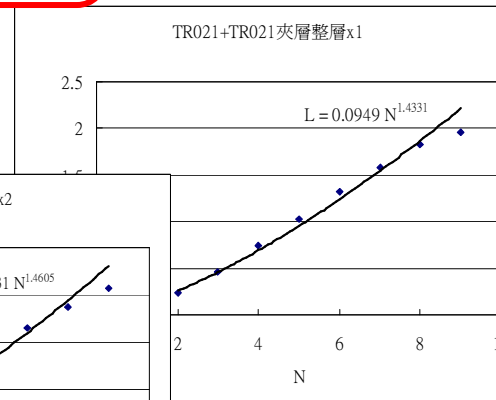
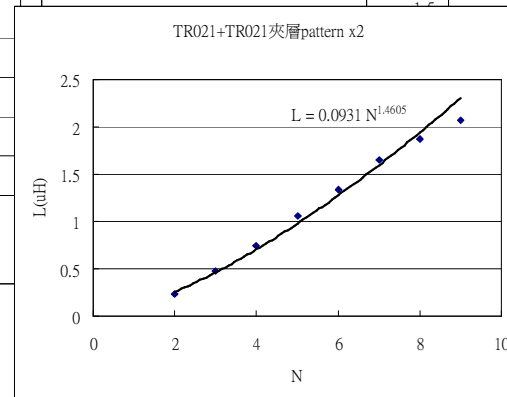
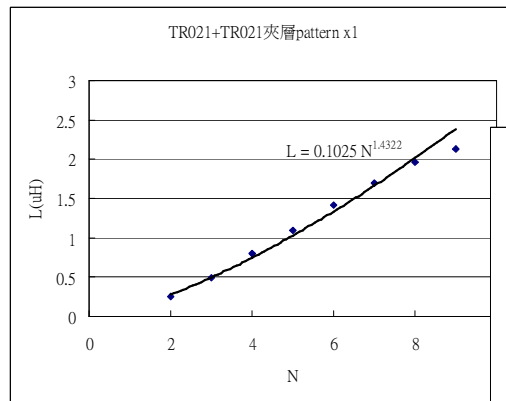
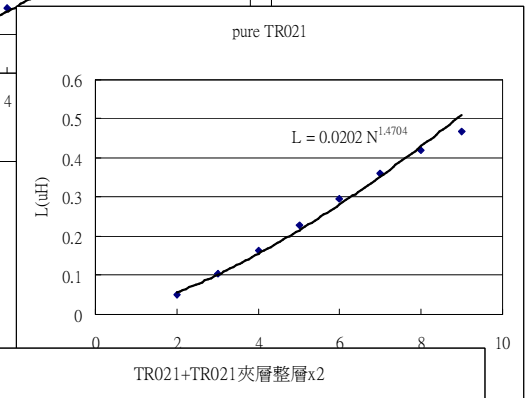
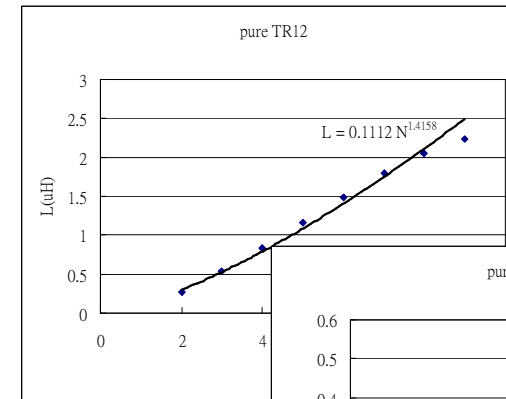
Without insertion layer



Equation of inductance $L=L_0N^x$

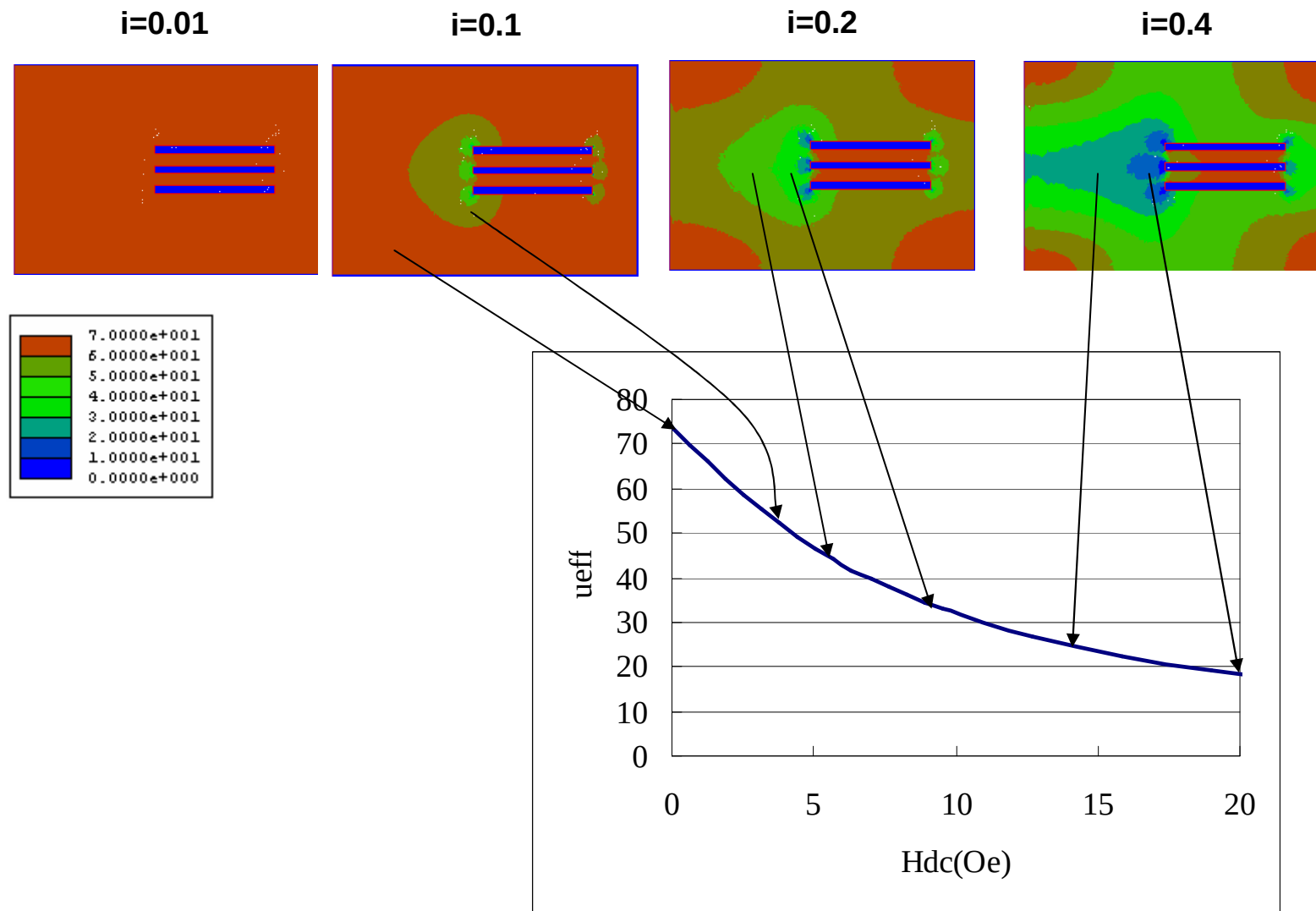
- $x=2$ for Idea case
- $x=1.41\sim 1.47$ for multilayer inductor

	$L_0(\mu\text{H})$	x
pure TR12	0.1112	1.4158
pure TR021	0.0202	1.4704
TR12 + TR021 IL _p x1	0.1025	1.4322
TR12 + TR021 IL _p x2	0.0931	1.4605
TR12 + TR021 IL _f x1	0.0949	1.4331
TR12 + TR021 IL _f x2	0.0823	1.4523



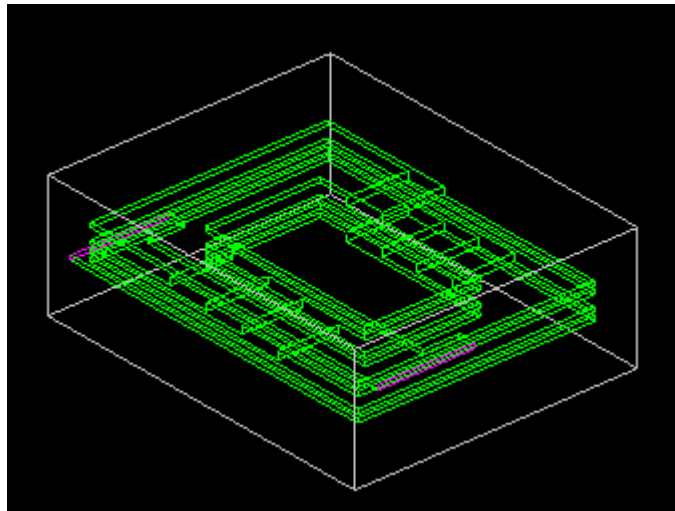
2D simulation (pure TR12)

Analysis of saturation and μ



3D simulation

Chip size: 2.3x1.85x0.8mm
coil pattern 1.2x0.75mm
3.5 and 4.5 turns
Line width: 0.4mm
Line thickness: 30μm
Ferrite thickness: 20μm
Use 3D axis symmetry model



Layers: same as 2D

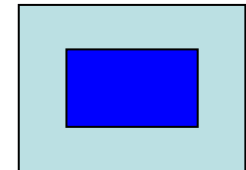
Without insertion layer

- pure TR12
- pure TR021

TR12 + TR021 insert layer

Insert in center area

- Single layer
- Two layer



TR12 + TR021 insert layer

Insert a full layer

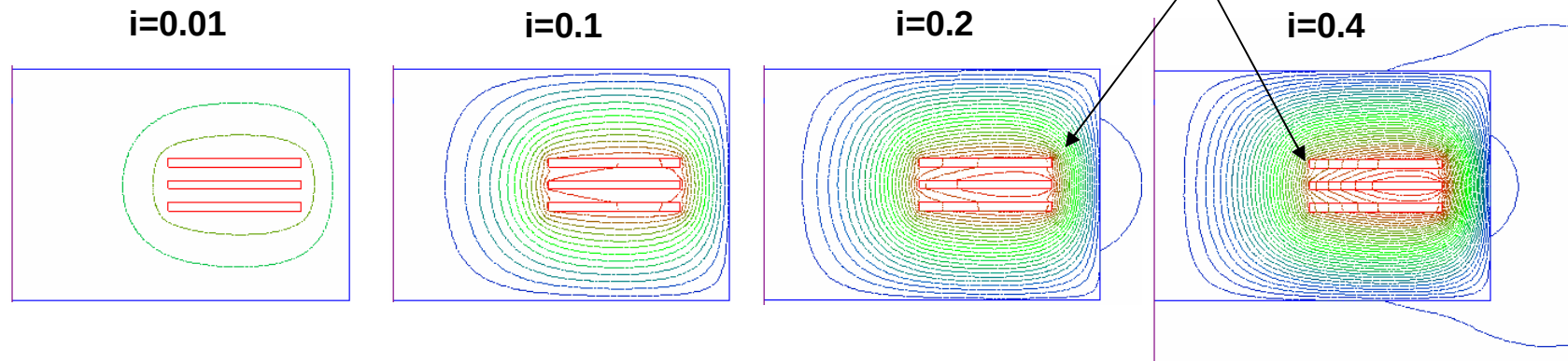
- Single layer
- Two layer



Flux distribution - 2D/3D simulation (pure TR12)

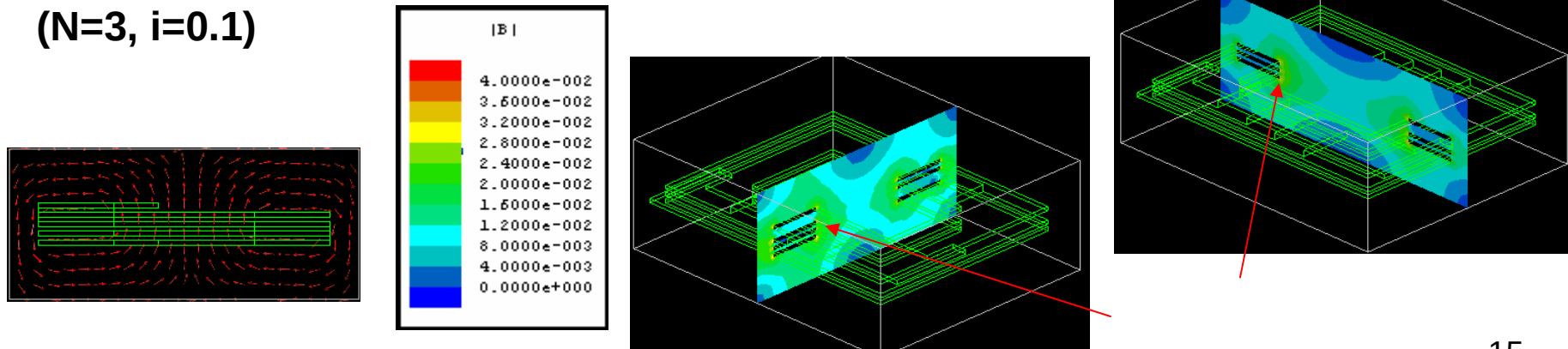
2D simulation

(N=3)



3D simulation

(N=3, $i=0.1$)

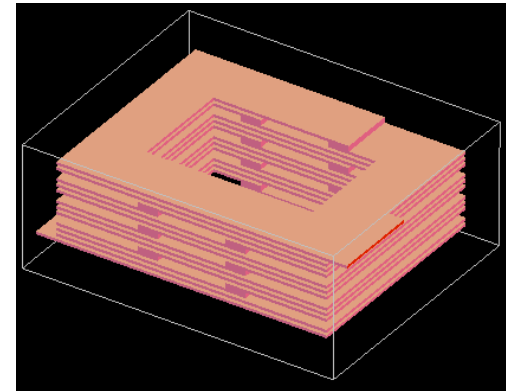


磁通密度於導線周圍最密集¹⁵

Summary of Simulation

3D model

- Real size 3D magnetic model
- Good inductance results from integration of flux and magnetic energy

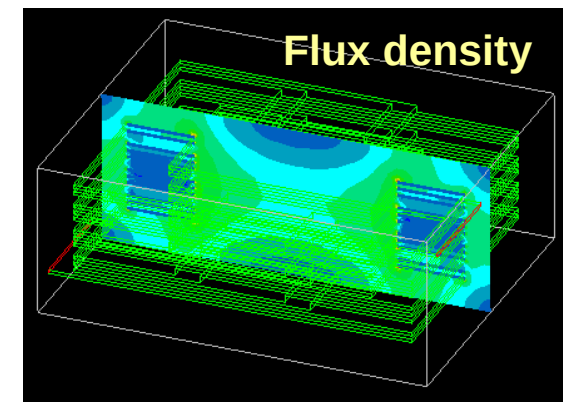


Simulation results

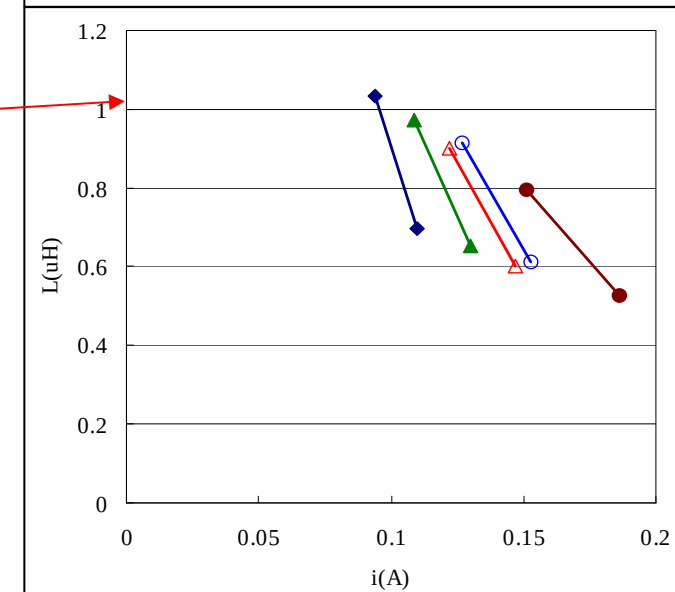
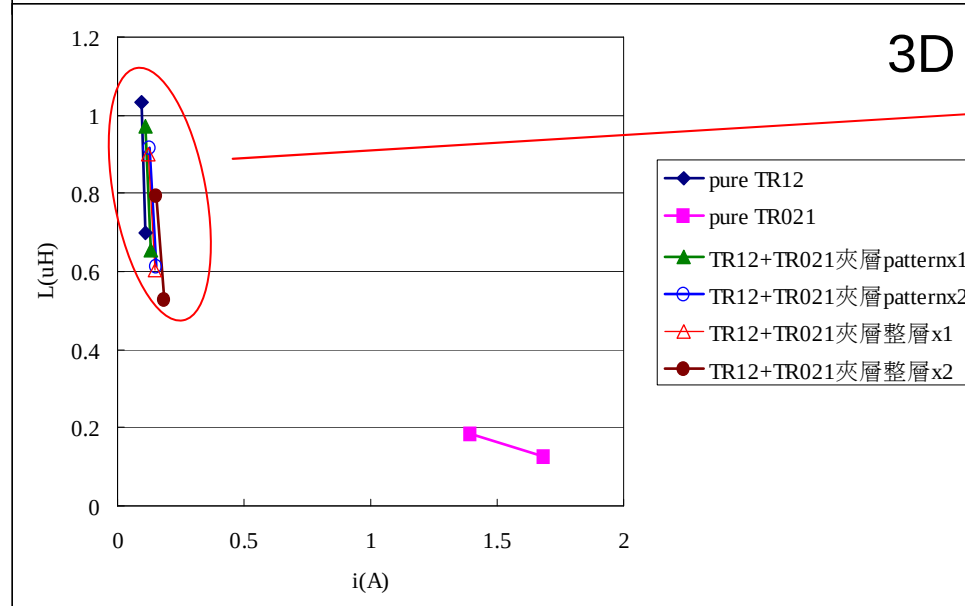
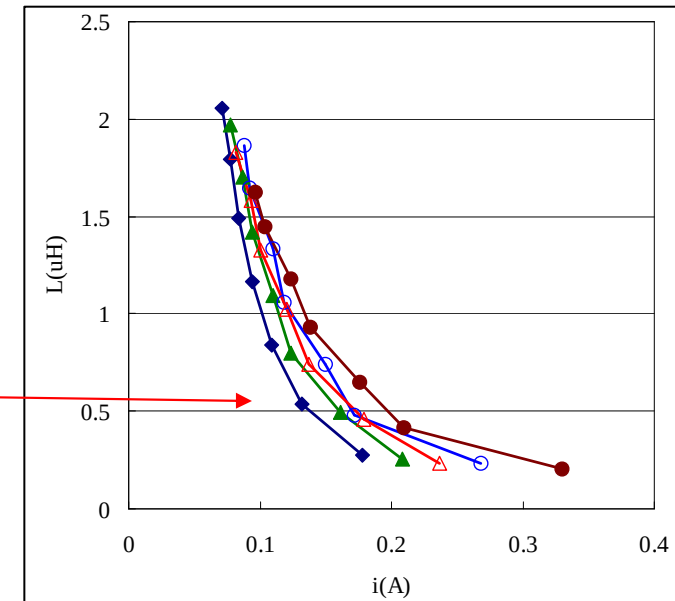
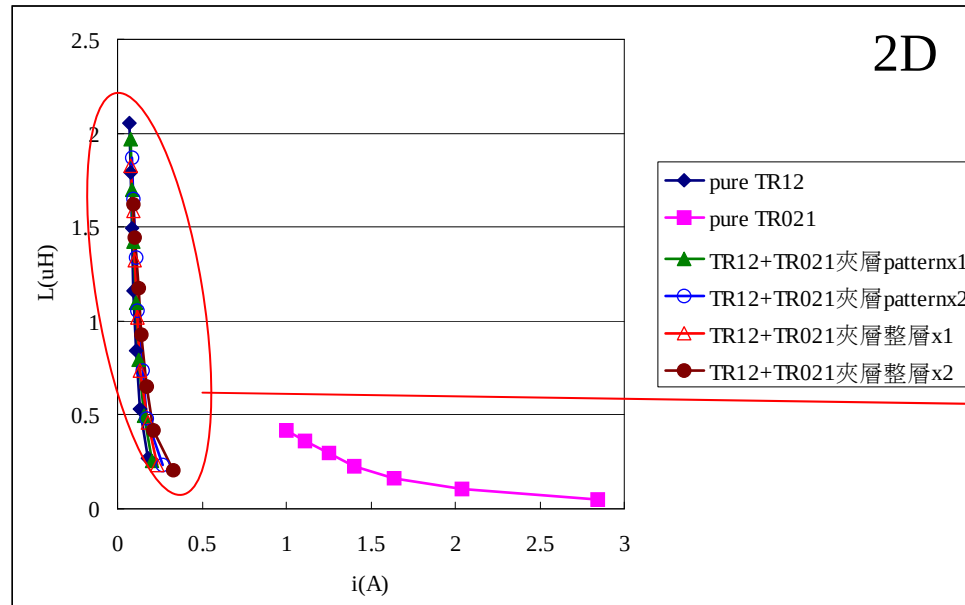
Multilayer model	2D	3D
Pure	10.7uH	11.3uH
2-layer insertion layer-full	3.05uH	3.1uH
2-layer insertion layer-partially	4.9uH	4.8uH



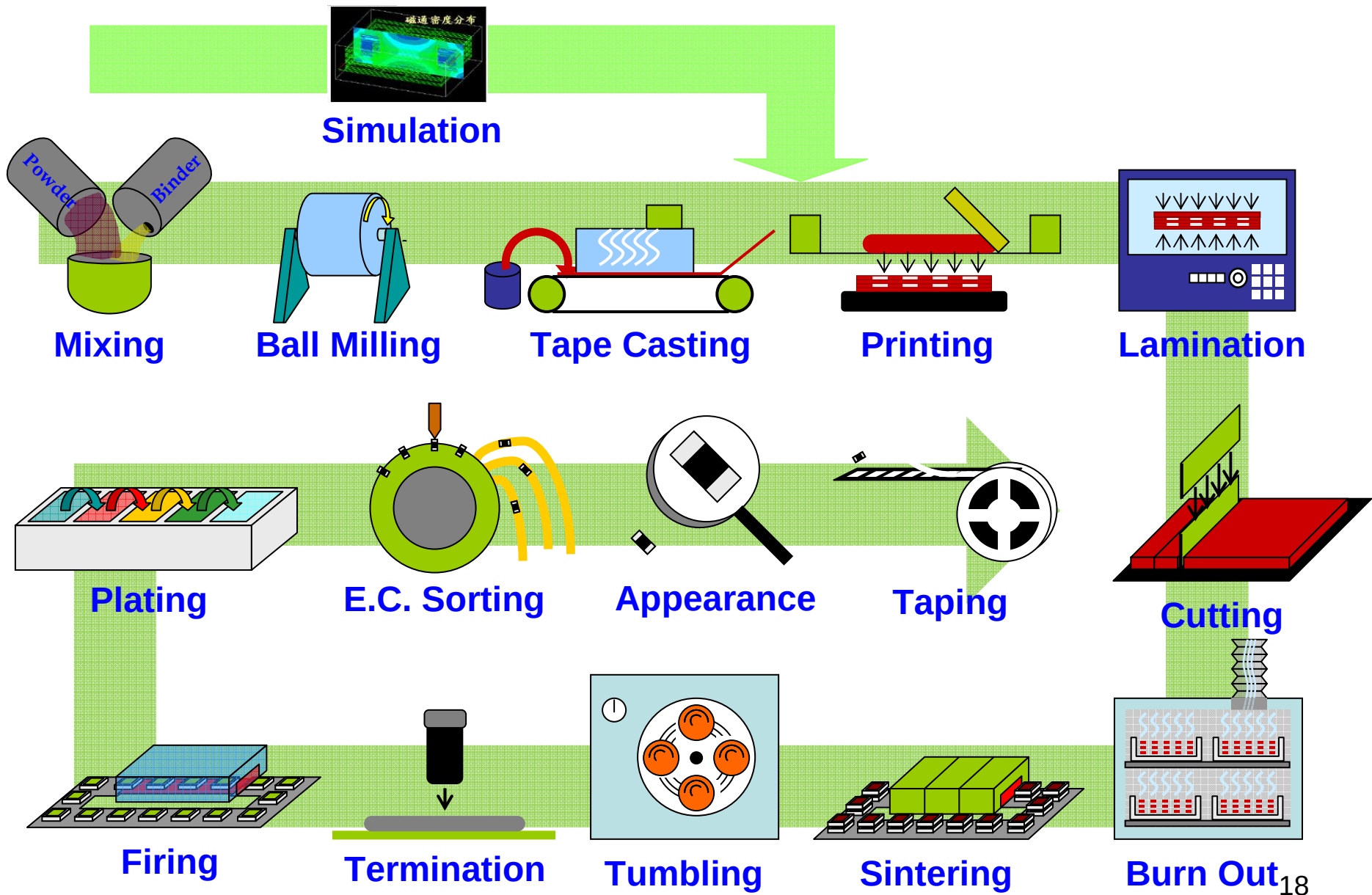
Measurement - L=4.3uH, deviation ~ 10%



Inductance vs. current from 2D/3D



Process of Multilayer inductor

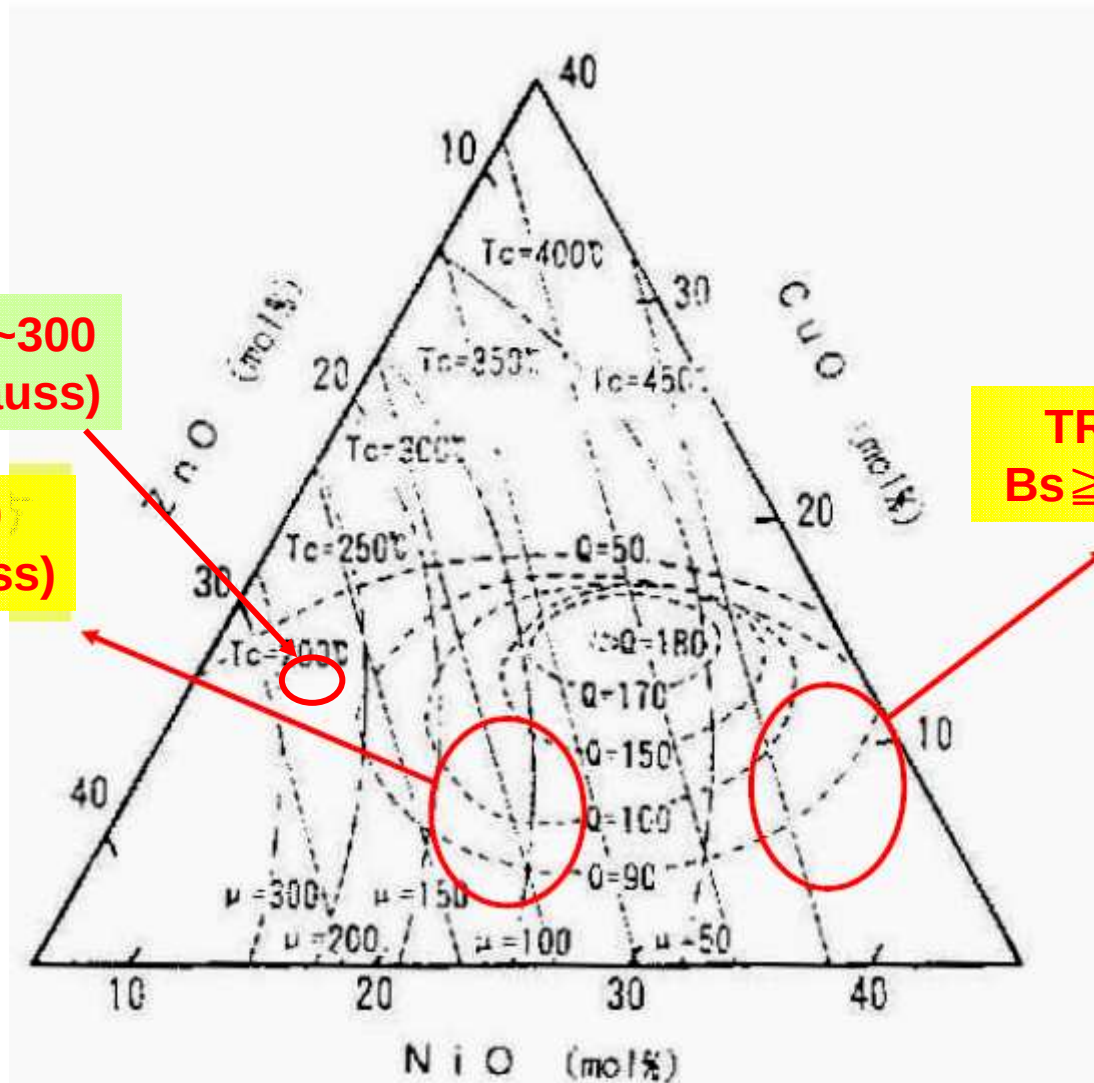


($\text{Fe}_2\text{O}_3=48\text{mole}\%$)

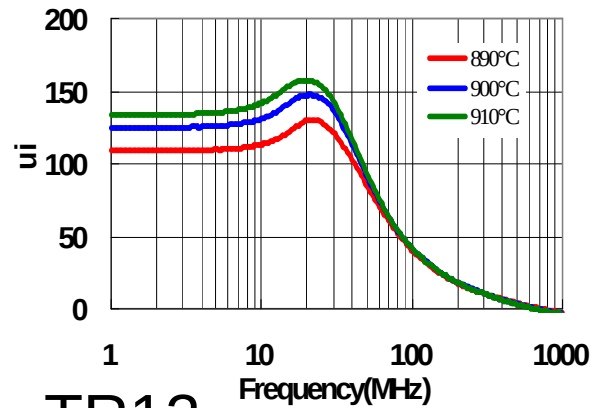
New TR30(ui~300
 $\text{Bs} \geq 4200$ Gauss)

TR12 (ui~120
 $\text{Bs} \geq 3700$ Gauss)

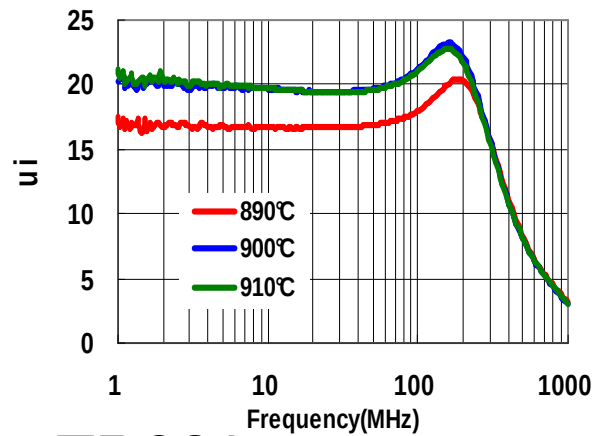
TR021 (ui~20
 $\text{Bs} \geq 2000$ Gauss)



Permeability (μ_i)

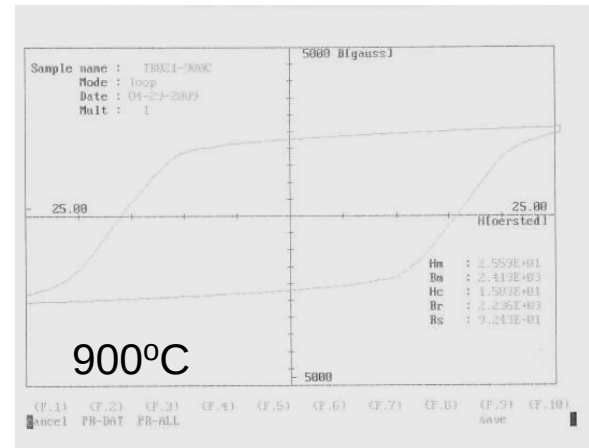
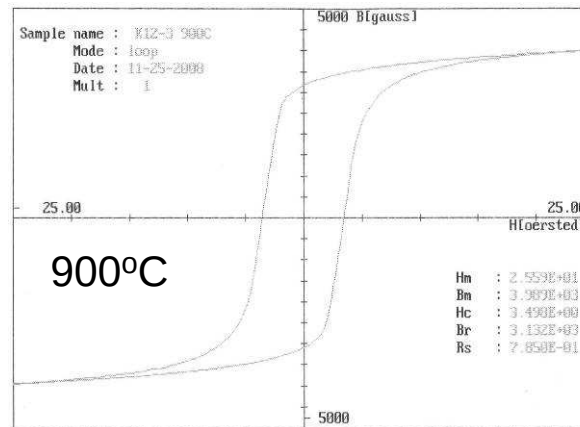


TR12

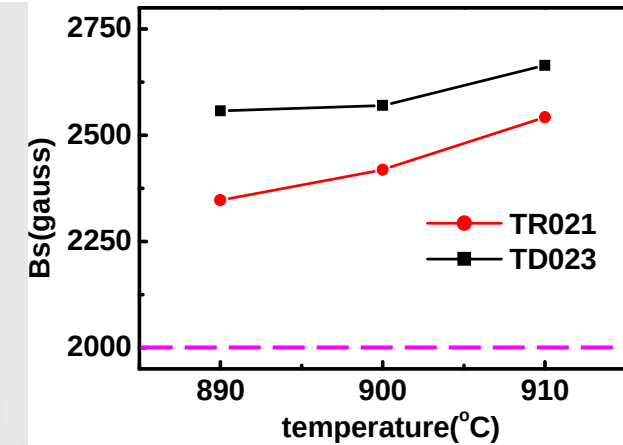
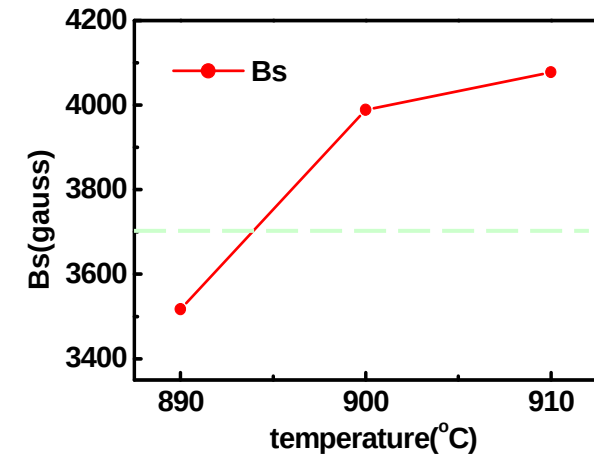


TR021

B-H Curve

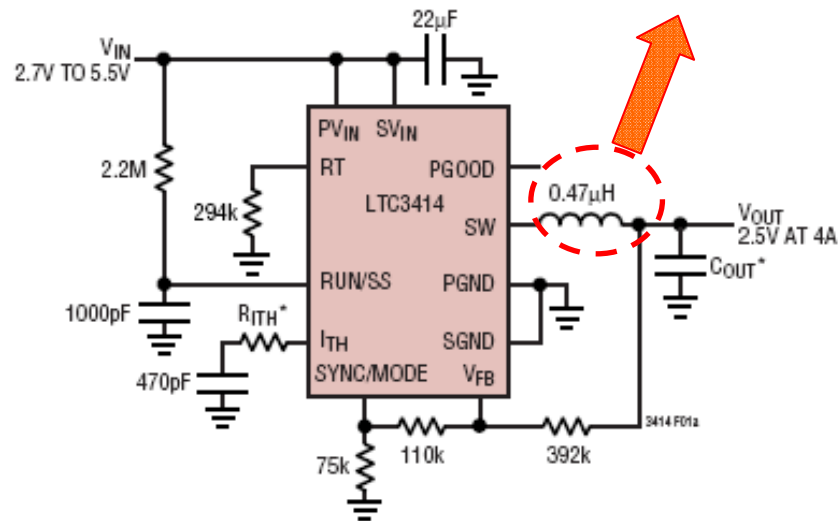
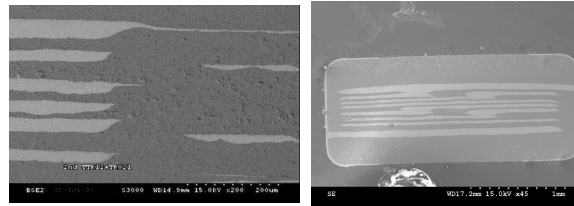


Flux density (B_s)



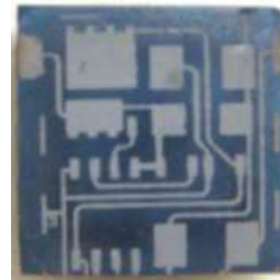
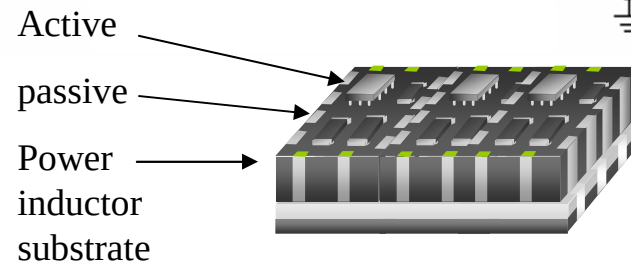
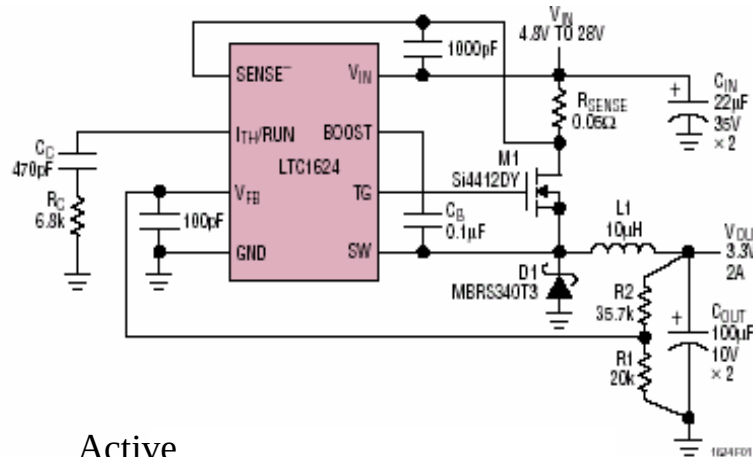
Results of multilayer power inductor and DC to DC converter

Type	L(μ H)	Rated current (A)	f max(MHz)	DCR ($m\Omega$)	L x W xT (mm)
Multilayer	0.47	1.8~2.4	6	59.2	2.5 x 2.0 x 0.9

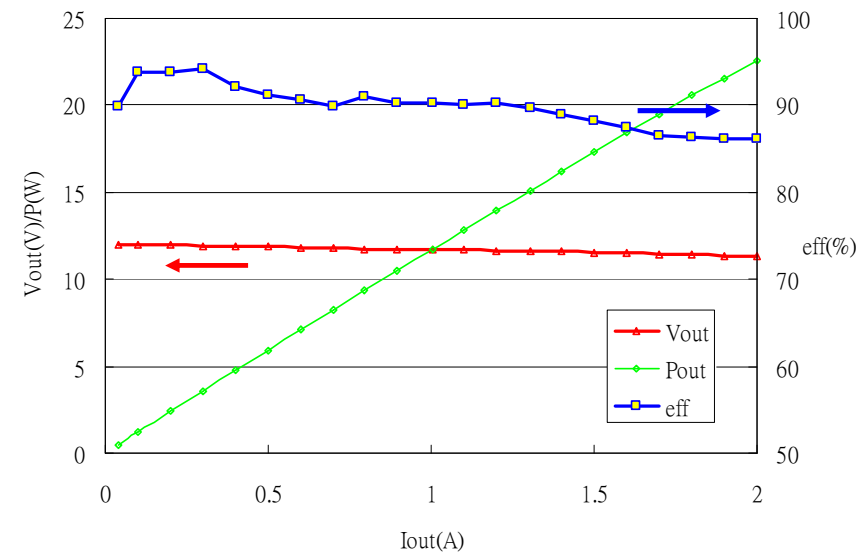
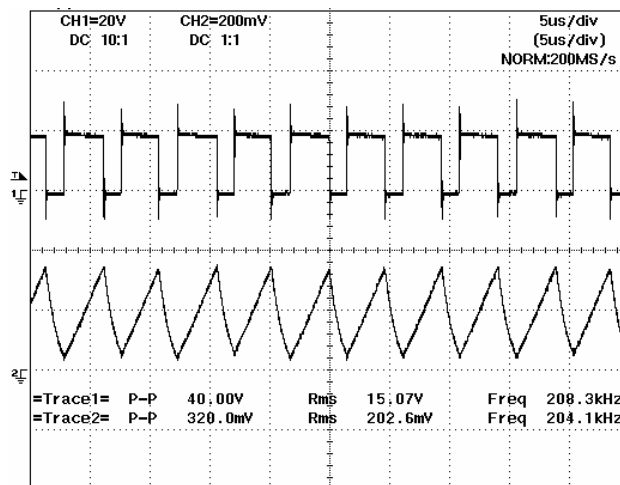


- V_{in} : 2.7~5.5V
- V_{out} : 2.5V
- I_{out} : $\geq 1.8A$
- $Eff.$: $\geq 85\%$
- f_s : $\sim 4MHz$

Integrated Multilayer Power Converter

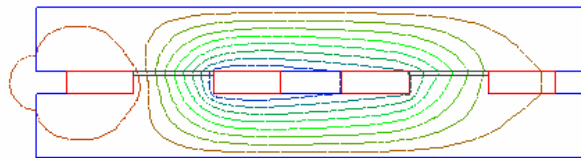
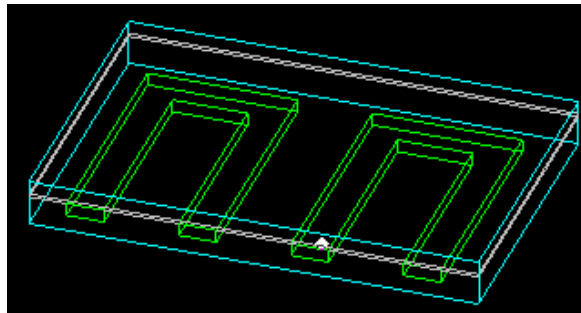


Pout (W)	~20
Efficiency (%)	>80
Power density (W/in3)	>200
Frequency (MHz)	0.2
Vin (V)	24
Vout (V)	12
Iout (A)	2
Size (mm)	15*15*6



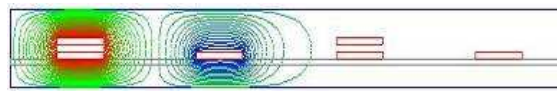
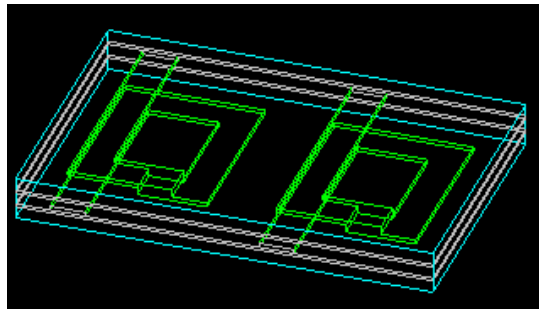
2D/3D model of multilayer Coupled Inductor

conventional
wire-wound type



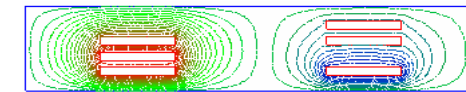
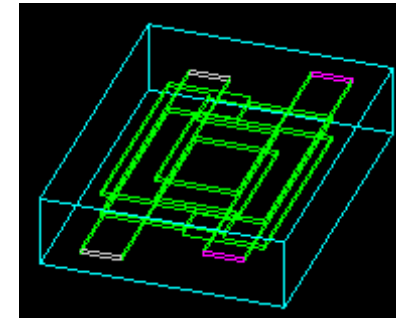
larger size

multilayer type
lateral coupling



weak coupling

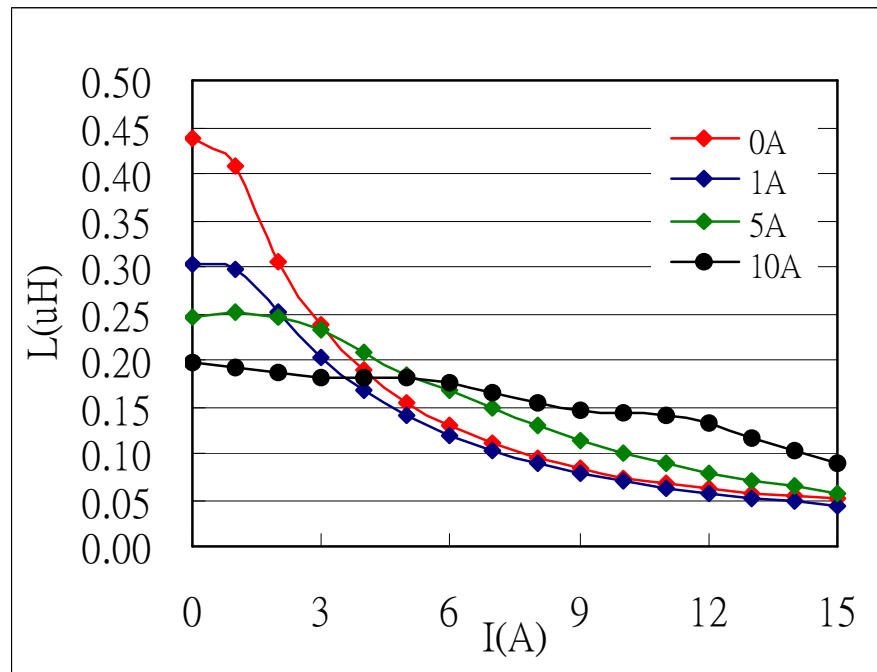
multilayer type
vertical coupling



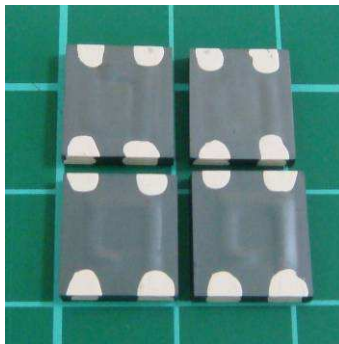
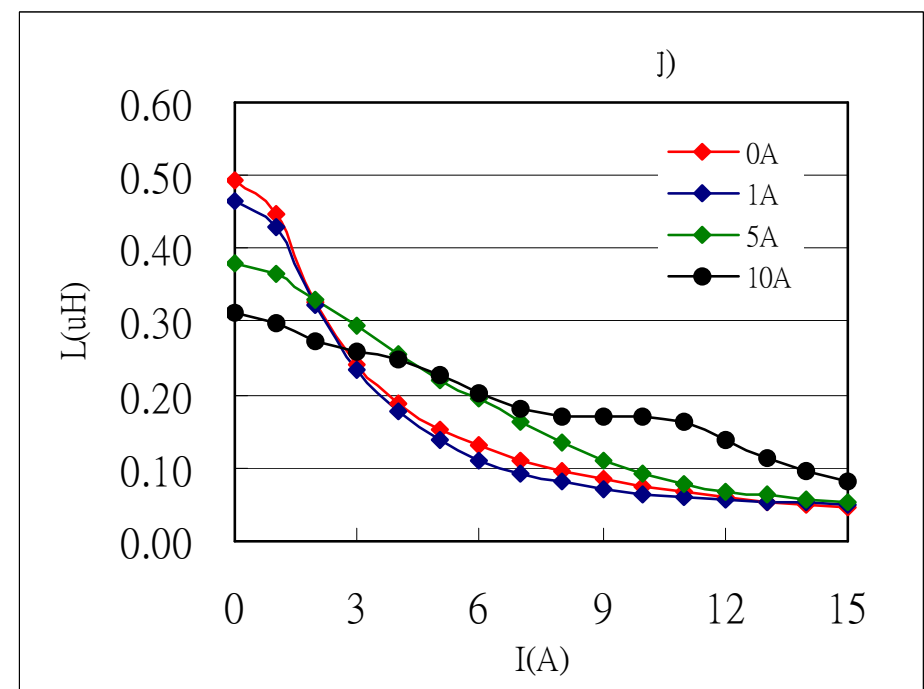
better coupling
coupling can be adjusted

DC current loading testing

2 coil wired - measurement



2 coil wired -simulation



Size:12*10*1.9(mm)

Summary

1. High B_s (0.42 Tesla) and high permeability (~ 300) low temperature co-fired Ni-Cu-Zn ferrite has been developed in order to further enhance the rated current of multilayer planar inductor.
2. The results of 2D and 3D simulation display a good consistency at inductance and rated current properties. Also the results shown the inductance are proportional to $N^{1.4}$ instead of N^2 . Low permeability layer will be enhance the current handling of the inductor.
3. The heterogeneous multilayer process provide very flexible way for planar inductor and the 252010 size Inductor has been demonstrated which the inductance $L=0.47\mu\text{H}$, $I_{\text{sat}} > 1.8\text{A}$ @6MHz (up to 2.4A). The rated current can up to 15A for coupled inductor.
4. The integrated multilayer power module approach the power density up to $200\text{W}/\text{inch}^3$ with efficiency in the range of 80%~90%.